TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC573P, TC74AC573F, TC74AC573FT

Octal D-Type Latch with 3-State Output

The TC74AC573 is an advanced high speed CMOS OCTAL LATCH fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

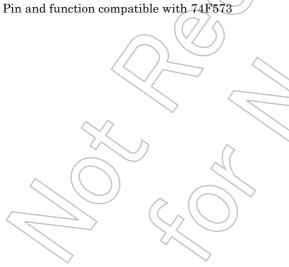
These 8-bit D-type latches are controlled by a latch enable input (LE) and a output enable input (\overline{OE}).

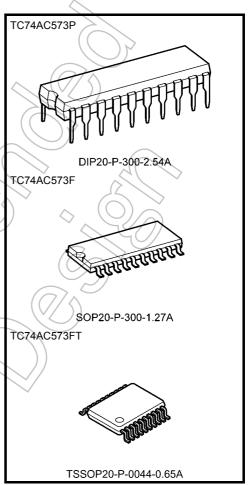
When the OE input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 6.0 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min) Capability of driving 50Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V



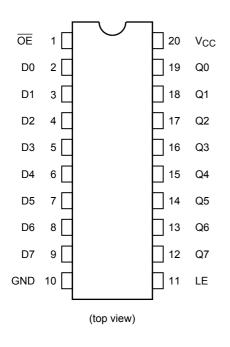


Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.)

Pin Assignment

IEC Logic Symbol



OE(1)	EN C1	
D0 (2) D1 (3) D2 (4) D3 (5) D4 (6) D5 (7) D6 (8) D7 (9)	1D Þ V	(19) Q0 (18) Q1 (17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

Truth Table

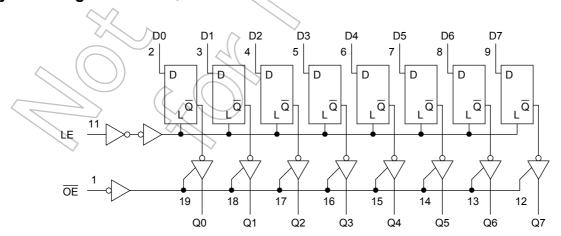
	Inputs	Output	
ŌE	LE	D	Q
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±200)) mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	VCC	2:0 to 5.5	V
Input voltage	// ŷ _{IN}	0 to V _{CC}	V
Output voltage	Vout	0 to V _{CC}	V
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 ($V_{CC} = 3.3 \pm 0.3 \text{ V}$) 0 to 20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

3



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			٦	Га = 25°C		Ta −40 to		Unit
Characteristics	Cymbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Omit
		_		2.0	1.50	_	1	1.50	_	
High-level input voltage	V_{IH}			3.0	2.10	_		2.10	_	V
_				5.5	3.85	_	1	3.85	_	
l				2.0	_	+0	0.50	_	0.50	
Low-level input voltage	V_{IL}		_	3.0	-//	7/\	0.90	_	0.90	V
				5.5	-(7	1.65	_	1.65	
				2.0	1.9	2.0	_	1.9	_	
			I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
High-level output	V _{OH}	V _{IN} = V _{IH} or V _{IL}		4.5	4.4	4.5		4.4	\rightarrow	V
voltage	٧ОН		$I_{OH} = -4 \text{ mA}$	(3.0)	2.58	_	-6	2.48	> —	
			I _{OH} = −24 mA	4.5	3.94	-0	(3.80) —	
			$I_{OH} = -75 \text{ mA}$ (Note)	5.5	_	_	1	3.85		
				2.0	_	0.0	0.1	<> −	0.1	
			I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output	V _{OL}	V _{IN} = V _{IH} or		4.5	_	0.0	0.1	_	0.1	V
voltage	VOL.	V _{IL}	I _{OL} = 12 mA	3.0			0.36	_	0.44	v
			I _{OL} = 24 mA	4.5	-		0.36	_	0.44	
			$I_{OL} = 75 \text{ mA}$ (Note)	5.5	\-))—	_	_	1.65	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5		_	±0.5	_	±5.0	μΑ
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	<u> </u>	_	±0.1	_	±1.0	μΑ
Quiescent supply current	lec	$V_{IN} = V_{C}$	5.5	_	_	8.0	_	80.0	μΑ	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit
		\supset	V _{CC} (V)	Limit	Limit	
Minimum pulse width			3.3 ± 0.3	7.0	7.0	ns
(LE)	tw (H)	_	5.0 ± 0.5	5.0	5.0	115
Minimum set-up time			3.3 ± 0.3	7.0	7.0	ns
Willimani set-up time	τ̈́S	_	5.0 ± 0.5	4.0	4.0	115
Minimum hold time	4		3.3 ± 0.3	1.0	1.0	ns
Minimum noid time	t _h	_	5.0 ± 0.5	1.0	1.0	115

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
			V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t _{pLH}	_	3.3 ± 0.3	_	9.4	15.4	1.0	17.6	ns
(LE-Q)	t _{pHL}		5.0 ± 0.5	_	6.6	9.9	1.0	11.3	
Propagation delay time	t _{pLH}	_	3.3 ± 0.3	_	9.4	16.0	1.0	18.2	ns
(Dn-Q)	t _{pHL}		5.0 ± 0.5	_	6.2	8.9	1.0	10.2	
Output enable time	t _{pZL}		3.3 ± 0.3	₹\	9.0	15.2	1.0	17.3	ns
Output enable time	t _{pZH}	1	5.0 ± 0.5	-	6.3	9.2	1.0	10.5	110
Output disable time	t _{pLZ}	_	3.3 ± 0.3	-((7.0	12.3	1.0	14.0	ns
Output disable time	t _{pHZ}	_	5.0 ± 0.5		6.0	8.8	1.0	10.0	113
Input capacitance	C _{IN}	_	<	1(-/	5	10	4	10	pF
Output capacitance	C _{OUT}	_	(=		10	- /	// <		pF
Power dissipation capacitance	C _{PD}		(Note)	5) ~	32 🔷	_((-	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

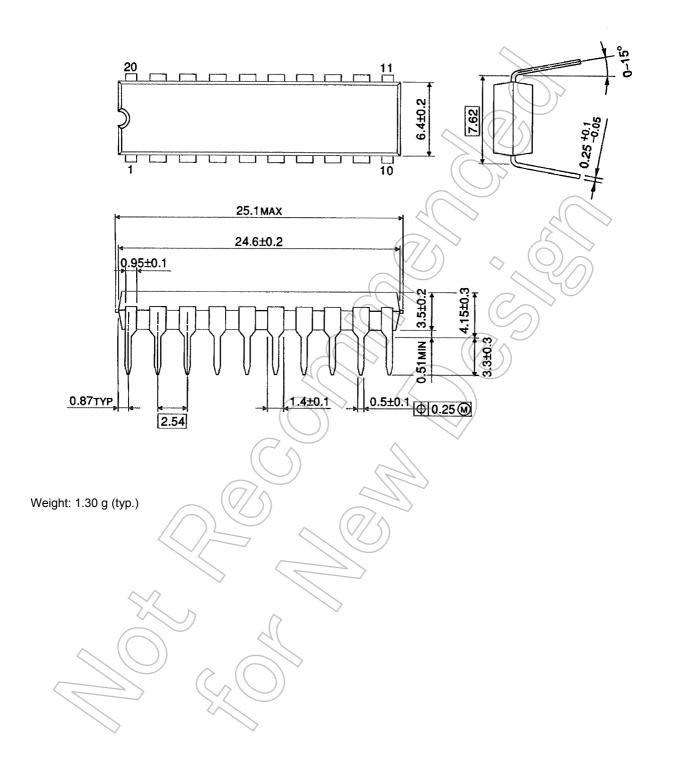
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per latch)$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

C_{PD} (total) = 21 + 11·n

Package Dimensions

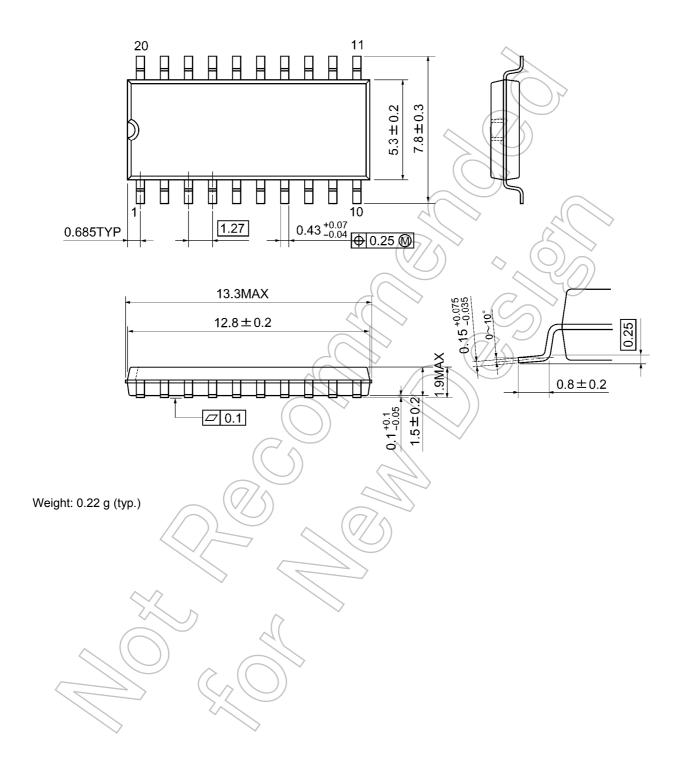
DIP20-P-300-2.54A Unit: mm





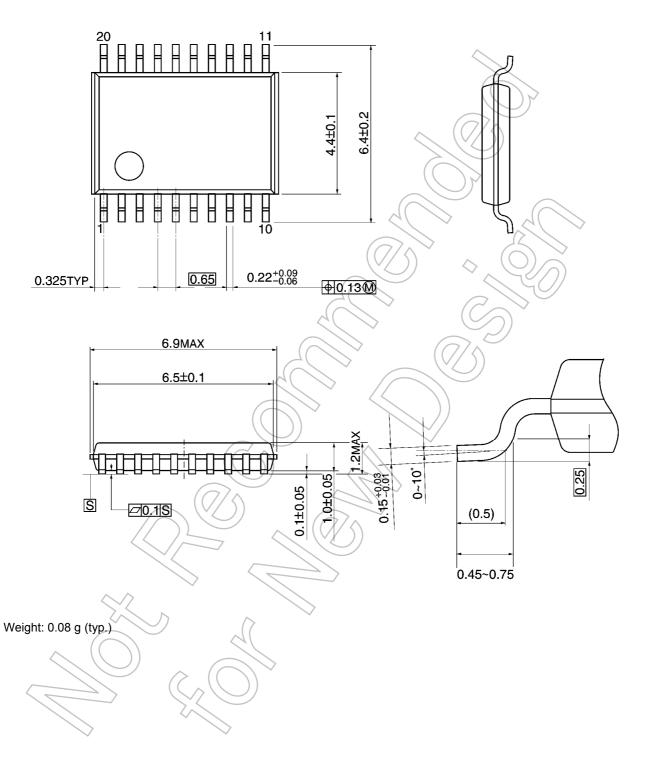
Package Dimensions

SOP20-P-300-1.27A Unit: mm



Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



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